

Title (en)  
SEMICONDUCTOR PACKAGE HAVING FILLER METAL OF GOLD/SILVER/COPPER ALLOY

Title (de)  
HALBLEITERKAPSELUNG MIT FÜLLMETALL AUS GOLD-/SILBER-/KUPFERLEGIERUNG

Title (fr)  
BOITIER A SEMI-CONDUCTEURS COMPRENANT UN METAL D'APPORT FORME D'UN ALLIAGE OR/ARGENT/CUIVRE

Publication  
**EP 1625618 A4 20100331 (EN)**

Application  
**EP 04752628 A 20040519**

Priority  
• US 2004015639 W 20040519  
• US 44254903 A 20030521

Abstract (en)  
[origin: US2004232529A1] A semiconductor package to which a potential difference is applied has two or more of the components thereof bound together using a filler metal. The filler metal is a solid solution structure in which the metallic components are atomically dispersed, and may comprise an alloy of gold, silver and copper. A preferred form of the filler metal comprises 60Au20Ag20Cu. Such filler metals in accordance with the invention provide the advantages of silver-based filler metals without the silver migration that leads to eventual shorting of the semiconductor package. When water condenses to form a continuous layer thereof within the semiconductor package due to moisture seeping into the package and temperature changes, the silver within the filler metal does not ionize, and therefore a buildup of silver deposits and eventual shorting of the package does not occur.

IPC 8 full level  
**H01L 23/02** (2006.01); **H01L 23/057** (2006.01); **H01L 23/10** (2006.01)

CPC (source: EP KR US)  
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Citation (search report)  
• [I] US 6261868 B1 20010717 - MILLER GERALD R [US], et al  
• [A] US 5043139 A 19910827 - CARNALL JR EDWARD [US], et al  
• [I] EP 0932199 A2 19990728 - SAINT GOBAIN NORTON IND CERAMI [US]  
• See references of WO 2004107436A1

Designated contracting state (EPC)  
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DOCDB simple family (publication)  
**US 2004232529 A1 20041125; US 6900525 B2 20050531**; AT E546833 T1 20120315; CA 2526484 A1 20041209; CA 2526484 C 20130430; CN 1802740 A 20060712; CN 1802740 B 20110330; EP 1625618 A1 20060215; EP 1625618 A4 20100331; EP 1625618 B1 20120222; HK 1086948 A1 20060929; IL 172051 A 20131231; JP 2007528590 A 20071011; JP 5097403 B2 20121212; KR 101109803 B1 20120227; KR 20060020634 A 20060306; WO 2004107436 A1 20041209

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